



# DMMT3906W

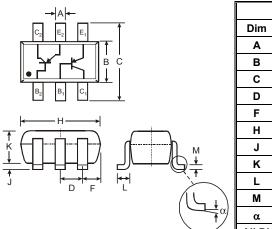
MATCHED PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

- Epitaxial Planar Die Construction
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% Matched Tolerance, h<sub>FE</sub>, V<sub>CE(SAT)</sub>, V<sub>BE(SAT)</sub>
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4 and 5)

## **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4B, See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.015 grams (approximate)



| SOT-363 |         |        |  |  |  |  |  |
|---------|---------|--------|--|--|--|--|--|
| Dim     | Min Max |        |  |  |  |  |  |
| Α       | 0.10    | 0.30   |  |  |  |  |  |
| в       | 1.15    | 1.35   |  |  |  |  |  |
| С       | 2.00    | 2.20   |  |  |  |  |  |
| D       | 0.65 N  | ominal |  |  |  |  |  |
| F       | 0.30    | 0.40   |  |  |  |  |  |
| н       | 1.80    | 2.20   |  |  |  |  |  |
| J       | —       | 0.10   |  |  |  |  |  |
| к       | 0.90    | 1.00   |  |  |  |  |  |
| L       | 0.25    | 0.40   |  |  |  |  |  |
| м       | 0.10    | 0.25   |  |  |  |  |  |
| α       | 0°      | 8°     |  |  |  |  |  |
| All Dim | ensions | in mm  |  |  |  |  |  |

| Maximum Ratings | @T <sub>A</sub> = 25°C unless otherwise specified |
|-----------------|---|
|-----------------|---|

| Characteristic                          | Symbol   | Value                             | Unit        |      |
|---|----------|-----------------------------------|-------------|------|
| Collector-Base Voltage                  |          | V <sub>CBO</sub>                  | -40         | V    |
| Collector-Emitter Voltage               |          | V <sub>CEO</sub>                  | -40         | V    |
| Emitter-Base Voltage                    |          | V <sub>EBO</sub>                  | -5.0        | V    |
| Collector Current - Continuous          |          | Ιc                                | -200        | mA   |
| Power Dissipation                       | (Note 3) | Pd                                | 200         | mW   |
| Thermal Resistance, Junction to Ambient | (Note 3) | $R_{	extsf{	heta}JA}$             | 625         | °C/W |
| Operating and Storage Temperature Range |          | T <sub>j</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

Notes: 1. Built with adjacent die from a single wafer.

No purposefully added lead.

 Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



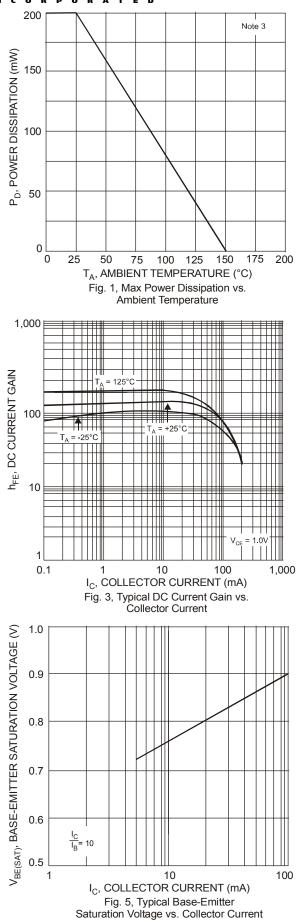
Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

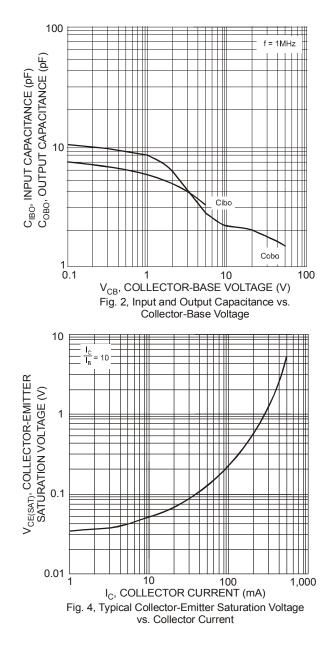
|          |                      |  |  | · · · · ·  |   |
|----------|----------------------|--|--|--|---|
|          | Symbol               | Min  | Max  | Unit   | Test Condition  |
|          |                      |  | 1  | 1  |   |
|          | V <sub>(BR)CBO</sub> | -40  | _  |  | $I_{\rm C} = -10 \mu A, I_{\rm E} = 0$  |
|          | $V_{(BR)CEO}$        | -40  |  | -  | I <sub>C</sub> = -1.0mA, I <sub>B</sub> = 0   |
|          | $V_{(BR)EBO}$        | -5.0   |  | V  | $I_{E} = -10\mu A$ , $I_{C} = 0$  |
|          | I <sub>CEX</sub>     | _  | -50  | nA   | $V_{CE} = -30V, V_{EB(OFF)} = -3.0V$  |
|          | I <sub>BL</sub>      | _  | -50  | nA   | $V_{CE} = -30V, V_{EB(OFF)} = -3.0V$  |
|          |                      |  | •  | •  | • • • • • • • • • • • • • • • • • • •   |
|          |                      | 60   |  |  | $I_{C} = -100 \mu A, V_{CE} = -1.0 V$   |
|          |                      | 80   |  |  | $I_{C} = -1.0 \text{mA}, V_{CE} = -1.0 \text{V}$  |
| (Note 7) | h <sub>FE</sub>      | 100  | 300  |  | $I_{C} = -10 \text{mA}, V_{CE} = -1.0 \text{V}$   |
|          |                      |  | —  |  | $I_{C} = -50 \text{mA}, V_{CE} = -1.0 \text{V}$   |
|          |                      | 30   | —  |  | $I_{C} = -100 \text{mA}, V_{CE} = -1.0 \text{V}$  |
| (Note 7) | Variant              |  | -0.25  | V  | I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA   |
| (10007)  | VCE(SAT)             |  |  | •  | I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA   |
| (Note 7) | VRE(SAT)             | -0.65  |  | v  | $I_{\rm C}$ = -10mA, $I_{\rm B}$ = -1.0mA   |
| (        | . ,                  | _  |  |  | I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA   |
|          | $\Delta V_{BE}$      | _  | -1   | mV   | $V_{CE} = -5V, I_C = -2mA$  |
|          | 0                    |  | 4.5  |  |   |
|          |                      |  |  |  | $V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$   |
|          | C <sub>ibo</sub>     |  | -  |  | $V_{EB} = -0.5V$ , f = 1.0MHz, I <sub>C</sub> = 0                                       |
|          | h <sub>ie</sub>      |  |  |  |   |
|          | h <sub>re</sub>      | -  | -  | x 10⁴  | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA,  |
|          | h <sub>fe</sub>      | 100  | 400  | —  | f = 1.0kHz  |
|          | h <sub>oe</sub>      | 3.0  | 60   | μS   |   |
|          | f <sub>T</sub>       | 250  | _  | MHz  | V <sub>CE</sub> = -20V, I <sub>C</sub> = -10mA,<br>f = 100MHz                           |
|          | NF                   | _  | 4.0  | dB   | V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -100μA,<br>R <sub>S</sub> = 1.0kΩ, f = 1.0kHz |
|          |                      |  |  | •  |   |
|          | t <sub>d</sub>       | _  | 35   | ns   | $V_{CC} = -3.0V, I_{C} = -10mA,$  |
|          | tr                   |  | 35   | ns   | $V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$   |
|          |                      |  | 225  | ns   | $V_{CC} = -3.0V, I_{C} = -10mA,$  |
|          |                      | _  | 75   | ns   | $I_{B1} = I_{B2} = -1.0$ mA   |
|          | . ,                  | V(BR)EBO   ICEX   IBL   (Note 7)   hFE   (Note 7)   VCE(SAT)   (Note 7)   VBE(SAT)   ΔVBE   Cobo   Cibo   hie   hre   hfe   NF | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $                                  |

Notes: 6. 7.

Short duration pulse test used to minimize self-heating effect. The DC current gain,  $h_{FE}$ , (matched at  $I_C = -10$ mA and  $V_{CE} = -1.0$ V) Collector Emitter Saturation Voltage,  $V_{CE(SAT)}$ , and Base Emitter Saturation Voltage,  $V_{BE(SAT)}$  are matched with typical matched tolerances of 1% and maximum of 2%.







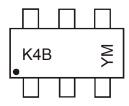


### Ordering Information (Note 8)

| Device        | Packaging | Shipping         |  |  |
|---------------|-----------|------------------|--|--|
| DMMT3906W-7-F | SOT-363   | 3000/Tape & Reel |  |  |

Notes: 8. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



K4B = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

| Date Code Key |      |      |      |     |      |      |     |      |      |      |      |      |
|---------------|------|------|------|-----|------|------|-----|------|------|------|------|------|
| Year          | 2002 | 2003 | 2004 | 200 | 5 20 | 06 2 | 007 | 2008 | 2009 | 2010 | 2011 | 2012 |
| Code          | N    | Р    | R    | S   | 1    | Г    | U   | V    | W    | Х    | Y    | Z    |
|               |      |      |      |     |      |      |     |      |      |      |      |      |
| Month         | Jan  | Feb  | Mar  | Apr | May  | Jun  | Jul | Aug  | Sep  | Oct  | Nov  | Dec  |
|               |      |      |      |     |      |      |     |      |      |      |      |      |

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